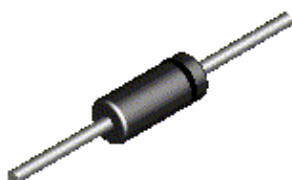


## 1N4150 / FDLL4150



DO-35



LL-34

THE PLACEMENT OF THE EXPANSION GAP  
HAS NO RELATIONSHIP TO THE LOCATION  
OF THE CATHODE TERMINAL

COLOR BAND MARKING		
DEVICE	1ST BAND	2ND BAND
FDLL4150	BLACK	ORANGE

### High Conductance Ultra Fast Diode

Sourced from Process 1R. See MMBD1201-1205 for characteristics.

#### Absolute Maximum Ratings\*

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
$W_{IV}$	Working Inverse Voltage	50	V
$I_O$	Average Rectified Current	200	mA
$I_F$	DC Forward Current	400	mA
$i_f$	Recurrent Peak Forward Current	600	mA
$i_{f(surge)}$	Peak Forward Surge Current		
	Pulse width = 1.0 second	1.0	A
	Pulse width = 1.0 microsecond	4.0	A
$T_{stg}$	Storage Temperature Range	-65 to +200	°C
$T_J$	Operating Junction Temperature	175	°C

\*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

**NOTES:**

- 1) These ratings are based on a maximum junction temperature of 200 degrees C.
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

#### Thermal Characteristics

TA = 25°C unless otherwise noted

Symbol	Characteristic	Max	Units
		1N / FDLL 4150	
$P_D$	Total Device Dissipation Derate above 25°C	500	mW
		3.33	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	300	°C/W

## High Conductance Ultra Fast Diode

(continued)

1N4150 / FDLL4150

### Electrical Characteristics

$T_A = 25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Max	Units
$B_V$	Breakdown Voltage	$I_R = 5.0 \mu\text{A}$	75		V
$I_R$	Reverse Current	$V_R = 50 \text{ V}$ $V_R = 50 \text{ V}, T_A = 150^\circ\text{C}$		100 100	nA $\mu\text{A}$
$V_F$	Forward Voltage	$I_F = 1.0 \text{ mA}$ $I_F = 10 \text{ mA}$ $I_F = 50 \text{ mA}$ $I_F = 100 \text{ mA}$ $I_F = 200 \text{ mA}$	540 660 760 820 0.87	620 740 860 920 1.0	mV mV mV mV V
$C_O$	Diode Capacitance	$V_R = 0, f = 1.0 \text{ MHz}$		2.5	pF
$T_{RR}$	Reverse Recovery Time	$I_F = I_R = 10 \text{ mA-}200 \text{ mA}, R_L = 100\Omega$ $I_F = I_R = 200 \text{ mA-}400 \text{ mA}, R_L = 100\Omega$		4.0 6.0	nS nS
$T_{FR}$	Forward Recovery Time	$I_F = 200 \text{ mA}, V_{FR} = 1.0 \text{ V}$		10	nS

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FACT™	QS™
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FAST®	SuperSOT™-3
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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

## PRODUCT STATUS DEFINITIONS

### Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.

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search

1N4150  
High Conduance Ultra Fast Diode

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General description

Sourced from Process 1R. See MMBD1201-1205 for characteristics.

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Product status/pricing/packaging

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Product	Product status	Pricing*	Package type	Leads	Package marking	Packing method
1N4150TR	Full Production	\$0.03	<a href="#">DO-35</a>	2	\$Y 1N 41 50	TAPE REEL
1N4150	Full Production	\$0.03	<a href="#">DO-35</a>	2	\$Y 1N 41 50	BULK

\* 1,000 piece Budgetary Pricing

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Models

Package & leads	Condition	Temperature range	Software version	Revision date
PSPICE				
DO-35-2	<a href="#">Electrical</a>	25°C	N/A	N/A

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